1.8V / 2.5V 10Gbps Equalizer Receiver with 1:6 Differential CML Outputs

Multi-Level Inputs w/ Internal Termination

Description

The NB7VQ1006M is a high performance differential 1:6 CML fanout buffer with a selectable Equalizer receiver. When placed in series with a Data path operating up to 10 Gb/s, the NB7VQ1006M will compensate the degraded data signal transmitted across a FR4 PCB backplane or cable interconnect and output six identical CML copies of the input signal. Therefore, the serial data rate is increased by reducing Inter–Symbol Interference (ISI) caused by losses in copper interconnect or long cables.

The EQualizer ENable pin (EQEN) allows the IN/\overline{IN} inputs to either flow through or bypass the Equalizer section. Control of the Equalizer function is realized by setting EQEN; When EQEN is set Low, the IN/\overline{IN} inputs bypass the Equalizer. When EQEN is set High, the IN/\overline{IN} inputs flow through the Equalizer. The default state at startup is LOW. As such, the NB7VQ1006M is ideal for SONET, GigE, Fiber Channel, Backplane and other Data distribution applications.

The differential inputs incorporate internal 50 Ω termination resistors that are accessed through the VT pin. This feature allows the NB7VQ1006M to accept various logic level standards, such as LVPECL, CML or LVDS. This feature provides transmission line termination at the receiver, eliminating external components. The outputs have the flexibility of being powered by either a 1.8 V or 2.5 V supply.

The NB7VQ1006M is a member of the GigaComm[™] family of high performance Clock/Data products.

Features

- Maximum Input Data Rate > 10 Gbps
- Maximum Input Clock Frequency > 7.5 GHz
- Backplane and Cable Interconnect Compensation
- 225 ps Typical Propagation Delay
- 30 ps Typical Rise and Fall Times
- Differential CML Outputs, 400 mV Peak-to-Peak, Typical
- Operating Range: $V_{CC} = 1.71 \text{ V}$ to 2.625 V, GND = 0 V
- Internal Input Termination Resistors, 50 Ω
- QFN-24 Package, 4 mm x 4 mm
- -40°C to +85°C Ambient Operating Temperature
- These are Pb-Free Devices*

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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MARKING DIAGRAM*



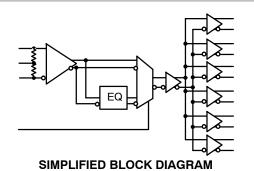
QFN-24 MN SUFFIX CASE 485L ONB7V Q1006M ALYW•

= Assembly Location

L = Wafer Lot Y = Year W = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

*For additional marking information, refer to Application Note AND8002/D.



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

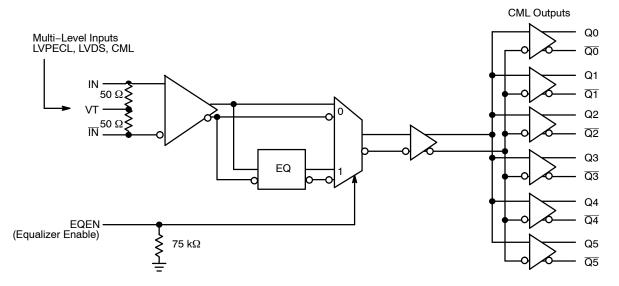


Figure 1. Detailed Block Diagram of NB7VQ1006M

Table 1. EQUALIZER ENABLE FUNCTION

EQEN Function			
0	$IN/I\overline{N}$ Inputs Bypass the EQualizer Section		
1	IN/IN Inputs Flow through the EQualizer Section		

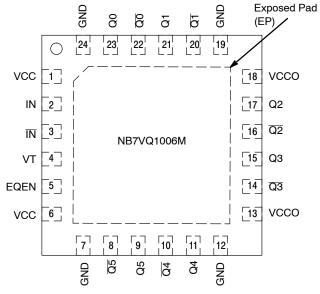


Figure 2. QFN-24 Lead Pinout (Top View)

Table 2. PIN DESCRIPTION

Pin	Name	I/O	Description
1	VCC		Positive Supply Voltage for the Core Logic
2	IN	LVPECL, CML, LVDS Input	Non-inverted Differential Clock/Data Input. (Note 1)
3	ĪN	LVPECL, CML, LVDS Input	Inverted Differential Clock/Data Input. (Note 1)
4	VT		Internal 50 Ω Termination Pin for IN and $\overline{\text{IN}}$
5	EQEN	LVCMOS Input	Equalizer Enable Input; pin will default LOW when left open (has internal pull-down resistor)
6	VCC		Positive Supply Voltage for the Core Logic
7	GND		Negative Supply Voltage
8	Q 5	CML	Inverted Differential Output. Typically terminated with 50 Ω resistor to V_{CC} .
9	Q5	CML	Non-inverted Differential Output. Typically terminated with 50 Ω resistor to V _{CC} .
10	Q4	CML	Inverted Differential Output. Typically terminated with 50 Ω resistor to V_{CC} .
11	Q4	CML	Non-inverted Differential Output. Typically terminated with 50 Ω resistor to V _{CC} .
12	GND		Negative Supply Voltage
13	VCCO		Positive Supply Voltage for the pre-amplifier and output buffer
14	Q3	CML	Inverted Differential Output. Typically terminated with 50 Ω resistor to V_{CC} .
15	Q3	CML	Non-inverted Differential Output. Typically terminated with 50 Ω resistor to V _{CC} .
16	Q2	CML	Inverted Differential Output. Typically terminated with 50 Ω resistor to V_{CC} .
17	Q2	CML	Non-inverted Differential Output. Typically terminated with 50 Ω resistor to V _{CC} .
18	VCCO		Positive Supply Voltage for the pre-amplifier and output buffer
19	GND		Negative Supply Voltage
20	Q1	CML	Inverted Differential Output. Typically terminated with 50 Ω resistor to V_{CC} .
21	Q1	CML	Non-inverted Differential Output. Typically terminated with 50 Ω resistor to V _{CC} .
22	Q 0	CML	Inverted Differential Output. Typically terminated with 50 Ω resistor to V_{CC} .
23	Q0	CML	Non-inverted Differential Output. Typically terminated with 50 Ω resistor to V _{CC} .
24	GND		Negative Supply Voltage
-	EP	-	The Exposed Pad (EP) on the QFN-24 package bottom is thermally connected to the die for improved heat transfer out of package. The exposed pad must be attached to a heat-sinking conduit. The pad is electrically connected to GND and is recommended to be electrically connected to GND on the PC board.

In the differential configuration when the input termination pin (VT) is connected to a common termination voltage or left open, and if no signal is applied on IN/IN, then the device will be susceptible to self-oscillation.
 All VCC, VCCO and GND pins must be externally connected to the same power supply voltage to guarantee proper device operation.

Table 3. ATTRIBUTES

Charact	Value			
ESD Protection Human Body Model Machine Model		> 4 kV > 200 V		
Moisture Sensitivity (Note 3)	Level 1			
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in		
Transistor Count	244			
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test				

^{3.} For additional information, see Application Note AND8003/D.

Table 4. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC} , V _{CCO}	Positive Power Supply	GND = 0 V		3.0	V
VI	Input Voltage	GND = 0 V		-0.5 to V _{CC} + 0.5	V
V _{INPP}	Differential Input Voltage IN − IN			1.89	V
I _{IN}	Input Current Through R _T (50 Ω Resistor)			±40	mA
I _{OUT}	Output Current Through R _T (50 Ω Resistor)			±40	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient) (Note 4) TGSD 51-6 (2S2P Multilayer Test Board) with Filled Thermal Vias	0 lfpm 500 lfpm	QFN-24 QFN-24	37 32	°C/W °C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	QFN-24	11	°C/W
T _{sol}	Wave Solder Pb-Free			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

^{4.} JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

Table 5. DC CHARACTERISTICS – CML OUTPUT V_{CC} = V_{CCO} = 1.71 V to 2.625 V; GND = 0 V T_A = $-40^{\circ}C$ to $85^{\circ}C$

Symbol	Characteristic		Min	Тур	Max	Unit
POWER	SUPPLY CURRENT (Inputs and Outputs open)				•	
I _{CCO}	Power Supply Current, Core Logic Power Supply Current, Outputs	$V_{CC} = 2.5V$ $V_{CC} = 1.8V$ $V_{CCO} = 2.5V$ $V_{CCO} = 1.8V$		100 85 180 150	115 95 200 175	mA
CML OU	TPUTS (Notes 5 and 6) (Figure 10)	000				
V _{OH}	Output HIGH Voltage	V _{CCO} = 2.5 V V _{CCO} = 1.8 V	V _{CCO} – 40 2460 1760	V _{CCO} – 10 2490 1790	V _{CCO} 2500 1800	mV
V _{OL}	Output LOW Voltage	V _{CCO} = 2.5V V _{CCO} = 2.5V V _{CCO} = 1.8V V _{CCO} = 1.8V	V _{CCO} - 600 1900 V _{CCO} - 525 1275	V _{CCO} - 500 2000 V _{CCO} - 425 1375	V _{CCO} - 400 2100 V _{CCO} - 300 1500	mV
DATA/CL	OCK INPUTS (IN, IN) (Note 7) (Figures 6 & 7)				•	
V_{IHD}	Differential Input HIGH Voltage		1100		V _{CC}	mV
V_{ILD}	Differential Input LOW Voltage		GND		V _{CC} – 100	mV
V_{ID}	Differential Input Voltage (V _{IHD} V _{ILD})		100		1200	mV
I _{IH}	Input HIGH Current		-150	30	+150	μΑ
I _{IL}	Input LOW Current		-150	-40	+150	μΑ
CONTRO	DL INPUTS (EQEN)					
V _{IH}	Input HIGH Voltage		V _{CC} x 0.65		V _{CC}	mV
V_{IL}	Input LOW Voltage		GND		V _{CC} x 0.35	mV
I _{IH}	Input HIGH Current		-150	25	+150	μΑ
I _{IL}	Input LOW Current		-150	10	+150	μΑ
TERMIN	ATION RESISTORS					
R _{TIN}	Internal Input Termination Resistor		45	50	55	Ω
R _{TOUT}	Internal Output Termination Resistor		45	50	55	Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

^{5.} CML outputs loaded with 50 Ω to V_{CC} for proper operation.
6. Input and output parameters vary 1:1 with $V_{CC/}V_{CCO}$.
7. V_{IHD} , V_{ILD} , V_{ID} and V_{CMR} parameters must be complied with simultaneously.

Table 6. AC CHARACTERISTICS $V_{CC} = V_{CCO} = 1.71 \text{ V}$ to 2.625 V; GND = 0 V $T_A = -40 ^{\circ}\text{C}$ to 85 °C (Note 8)

Symbol	Characteristic		Тур	Max	Unit
f _{DATA}	Maximum Operating Input Data Rate				Gbps
f _{MAX}	Maximum Input Clock Frequency $V_{CC} = 2.5V$ $V_{CC} = 1.8V$	7.5 6.5			GHz
V _{OUTPP}	Output Voltage Amplitude EQEN = 0 or 1 $f_{in} \le 5.0 \text{ GHz V}_{CC} = 2.5 \text{V}$ (See Figures 4, Note 9) $f_{in} \le 7.5 \text{ GHz V}_{CC} = 2.5 \text{V}$	275 225	440 360		mV
	$f_{in} \le 5 \text{ GHz V}_{CC} = 1.8\text{V}$ $f_{in} \le 6.5 \text{ GHz V}_{CC} = 1.8\text{V}$	225 200	360 315		
V _{CMR}	Input Common Mode Range (Differential Configuration, Note 10) (Figure 8)	1050		V _{CC} – 50	mV
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential, IN/IN to Qn/Qn		225	315	ps
t _{PLH} TC	Propagation Delay Temperature Coefficient -40°C to +85°C		30		fs/°C
t _{DC}	Output Clock Duty Cycle		50	52	%
t _{SKEW}	Duty Cycle Skew (Note 11) Within Device Skew (Note 12) Device to Device Skew (Note 13)		0.15 10 20	1 25 40	ps
t _{JITTER}	Random Clock Jitter RJ(RMS), 1000 cycles (Note 14) EQEN = $1f_{in} \le 5.0$ GHz 5 GHz $\le f_{in} \le 7.5$ GHz		0.2 0.2	0.7 1.2	ps
	Deterministic Jitter (DJ) (Note 15) EQEN = 1, FR4 = 12", \leq 10 Gbps V_{CC} = 2.5 V V_{CC} = 1.8 V		3 3	40 20	
V _{INPP}	Input Voltage Swing (Differential Configuration) (Note 16) (Figure 6)			1200	mV
t _r , t _f	Output Rise/Fall Times Qn/Qn, (20% - 80%)		30	65	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 8. Measured using a 400 mV source, 50% duty cycle 1 GHz clock source. All outputs must be loaded with external 50 Ω to V_{CCO} . Input edge rates 40 ps (20% 80%).
- 9. Output voltage swing is a single-ended measurement operating in differential mode.
- 10. V_{CMR} min varies 1:1 with GND, V_{CMR} max varies 1:1 with V_{CC}. The V_{CMR} range is referenced to the most positive side of the differential input signal.
- 11. Duty cycle skew is measured between differential outputs using the deviations of the sum of T_{pw^-} and T_{pw^+} @ 5 GHz.
- 12. Within device skew compares coincident edges.
- 13. Device to device skew is measured between outputs under identical transition
- 14. Additive CLOCK jitter with 50% duty cycle clock signal.
- 15. Additive Peak-to-Peak jitter with input NRZ data at PRBS23.
- 16. Input voltage swing is a single-ended measurement operating in differential mode, with minimum propagation change of 25 ps.

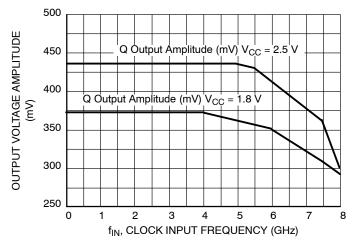


Figure 3. Output Voltage Amplitude (V_{OUTPP}) vs. Input Frequency (f_{in}) at Ambient Temperature (Typ), (EQEN = 0)

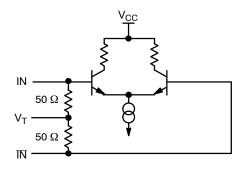
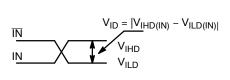


Figure 4. Input Structure



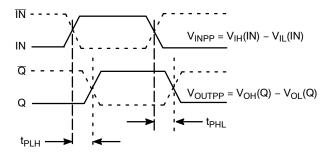


Figure 5. Differential Inputs Driven Differentially

Figure 6. AC Reference Measurement

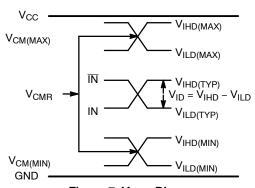


Figure 7. V_{CMR} Diagram

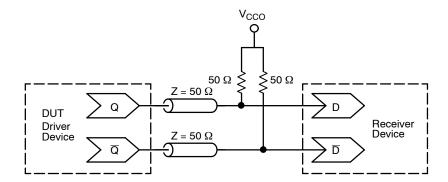


Figure 8. Typical Termination for CML Output Driver and Device Evaluation

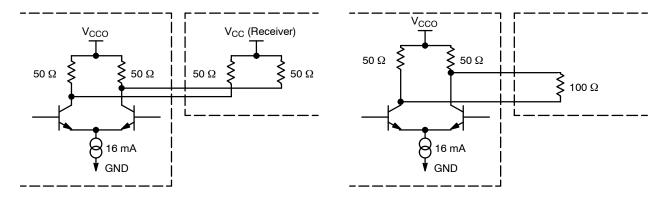


Figure 9. Typical CML Output Structure and Termination

Figure 10. Alternative Output Termination

APPLICATION INFORMATION

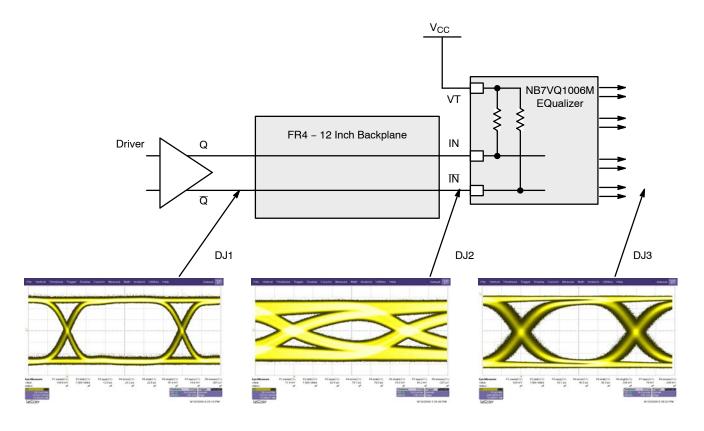


Figure 11. Typical NB7VQ1006 Equalizer Application and Interconnect with PRBS23 pattern at 7.0 Gbps

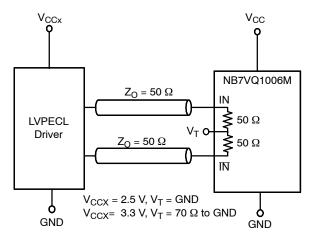


Figure 12. LVPECL Interface

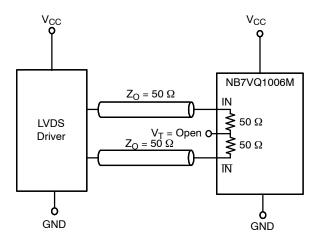


Figure 13. LVDS Interface

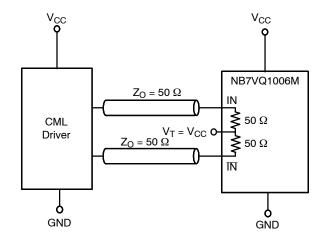


Figure 14. Standard 50 Ω Load CML Interface

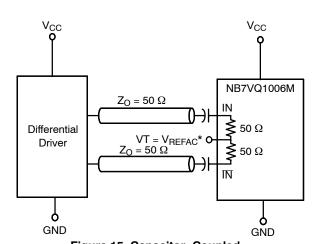


Figure 15. Capacitor-Coupled
Differential Interface
(VT Connected to External V_{REFAC})

ORDERING INFORMATION

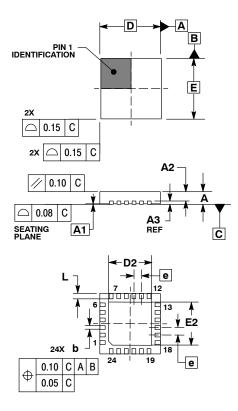
Device	Package	Shipping [†]
NB7VQ1006MMNG	QFN-24 (Pb-Free)	92 Units / Rail
NB7VQ1006MMNHTBG	QFN-24 (Pb-Free)	100 / Tape & Reel
NB7VQ1006MMNTXG	QFN-24 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*} V_{REFAC} bypassed to ground with a 0.01 μF capacitor

PACKAGE DIMENSIONS

QFN24, 4x4, 0.5P CASE 485L-01 ISSUE A



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.80	1.00		
A1	0.00	0.05		
A2	0.60	0.80		
A3	0.20 REF			
b	0.20	0.30		
D	4.00 BSC			
D2	2.70	2.90		
E	4.00 BSC			
E2	2.70	2.90		
е	0.50 BSC			
L	0.30	0.50		

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